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Has received an application for a patent for a new and useful invention. The title and description of the invention are enclosed. The requirements of law have been complied with, and it has been determined that a patent on the invention shall be granted under the law.

Therefore, this

United States Patent

Grants to the person or persons having title to this patent the right to exclude others from making, using or selling the invention throughout the United States of America for the term of seventeen years from the date of this patent, subject to the payment of maintenance fees as provided by law.

Bruce Lehman

Commissioner of Patents and Trademarks

Mayrie V. Turner

Attest

United States Patent [19]

Matsui

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[54] SEMICONDUCTOR MEMORY CIRCUIT

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[57] ABSTRACT

This semiconductor circuit includes a plurality of memory cell arrays arranged mutually adjacent in one direction, a plurality of first selection/sense amplifier circuits provided in the respective regions between mutually adjacent pairs of these memory cell arrays and make access to one of alternately defined odd-numbered or even-numbered memory cell trains in the order of arrangement, two units of second selection/sense amplifier circuits arranged on the outside of the memory cell arrays on both ends of the arrangement of the plurality of memory cell arrays and make access to one of the designated odd-numbered or even-numbered memory cell trains of the memory cell arrays on both ends, a plurality of data buses corresponding to the respective bits of data transferred in bit parallel between an external circuit, and a plurality of input and output switching circuits arranged and connected in one-to-one correspondence to the respective first and second selection/sense amplifier circuits connected to the plurality of data buses so as to have an equal number of memory cell trains capable of transferring data with these data buses, and a plurality of input and output switching circuits which transfer data with the first and the second selection/sense amplifier circuits in one-to-one correspondence.

3 Claims, 4 Drawing Sheets

